COMPLIANT

HALOGEN

FREE



Vishay Semiconductors

High Performance Schottky Rectifier, 20 A



PRIMARY CHARACTERISTICS							
I _{F(AV)}	20 A						
V _R	15 V						
V _F at I _F	See Electrical table						
I _{RM} max.	600 mA at 100 °C						
T _J max.	125 °C						
E _{AS}	10 mJ						
Package	TO-220AC 2L						
Circuit configuration	Single						

FEATURES

- 125 °C T_J operation (V_R < 5 V)
- · Single diode configuration
- · Optimized for OR-ing applications
- Ultra low forward voltage drop
- Guard ring for enhanced ruggedness and long term reliability
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- Designed and qualified according to JEDEC®-JESD 47
- Material categorization: for definitions of compliance please see <u>www.vishav.com/doc?99912</u>

DESCRIPTION

The Schottky rectifier module has been optimized for ultra low forward voltage drop specifically for the OR-ing of parallel power supplies. The proprietary barrier technology allows for reliable operation up to 125 °C junction temperature. Typical applications are in parallel switching power supplies, converters, reverse battery protection, and redundant power subsystems.

MAJOR RATINGS AND CHARACTERISTICS								
SYMBOL	VALUES	UNITS						
I _{F(AV)}	Rectangular waveform	20	Α					
V_{RRM}		15	V					
I _{FSM}	$t_p = 5 \mu s sine$	700	Α					
V _F	19 A _{pk} , T _J = 125 °C (typical)	0.25	V					
T _J	Range	-55 to +125	°C					

VOLTAGE RATINGS								
PARAMETER	SYMBOL	VS-20L15T-M3	UNITS					
Maximum DC reverse voltage	V_{R}	15	V					
Maximum working peak reverse voltage	V_{RWM}	15	V					

ABSOLUTE MAXIMUM RATINGS								
PARAMETER	SYMBOL	TEST COND	ITIONS	VALUES	UNITS			
Maximum average forward current See fig. 5	I _{F(AV)}	50 % duty cycle at T _C = 85 °C,	20					
Maximum peak one cycle non-repetitive surge current	o po onto or o po root, paro		700	Α				
See fig. 7	I _{FSM}	10 ms sine or 6 ms rect. pulse	V _{RRM} applied	330				
Non-repetitive avalanche energy	E _{AS}	T _J = 25 °C, I _{AS} = 2 A, L = 6 mH		10	mJ			
Repetitive avalanche current	I _{AR}	Current decaying linearly to zer Frequency limited by T_J maxim	2	Α				



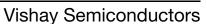
Vishay Semiconductors

ELECTRICAL SPECIFICATIONS								
PARAMETER	SYMBOL	TEST CONDITIONS			MAX.	UNITS		
		19 A	T _{.1} = 25 °C	ı	0.41	V		
Forward voltage drop	V _{FM} ⁽¹⁾	40 A	1]=25 0	1	0.52			
See fig. 1	VFM ('')	19 A	T _{.1} = 125 °C	0.25	0.33			
		40 A	1J = 125 C	0.37	0.50			
Reverse leakage current	I _{RM} ⁽¹⁾	T _J = 25 °C	V _B = Rated V _B	-	10	mA		
See fig. 2	IRM ("/	T _J = 100 °C	v _R = nateu v _R	-	600	IIIA		
Threshold voltage	V _{F(TO)}	$T_1 = T_1 \text{ max.}$		0.182		V		
Forward slope resistance	r _t	ij=ijiliax.	7.6		mΩ			
Maximum junction capacitance	C _T	$V_R = 5 V_{DC}$, (test signal ran	-	2000	pF			
Typical series inductance	L _S	Measured lead to lead 5 m	8	-	nH			
Maximum voltage rate of change	dV/dt	Rated V _R	10	000	V/µs			

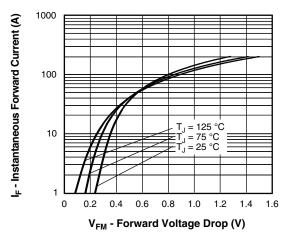
Note

 $^{(1)}\,$ Pulse width < 300 µs, duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS								
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS				
Maximum junction temperature range	T_J		-55 to +125	°C				
Maximum storage temperature range	T _{Stg}		-50 to +150	C				
Maximum thermal resistance, junction to case	R _{thJC}	DC operation See fig. 4	1.5					
Typical thermal resistance, case to heatsink	R _{thCS}	Mounting surface, smooth and greased (for TO-220)	0.50 °C/					
Maximum thermal resistance, junction to ambient	R _{thJA}	DC operation (for D ² PAK)	40					
Approximate weight			2	g				
Approximate weight			0.07	OZ.				
Mounting torque minimum		Non-lubricated threads	6 (5)	kgf · cm				
Mounting torque maximum		Non-lubricated tilleads	12 (10)	(lbf·in)				
Marking device		Case style TO-220AC 2L	20L1	5T				







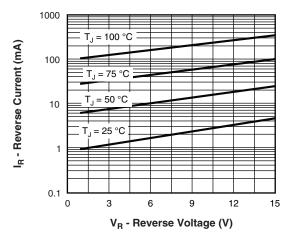


Fig. 1 - Maximum Forward Voltage Drop Characteristics

Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

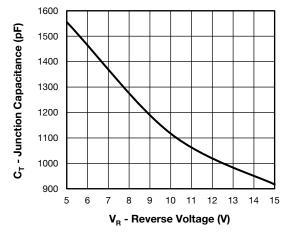


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

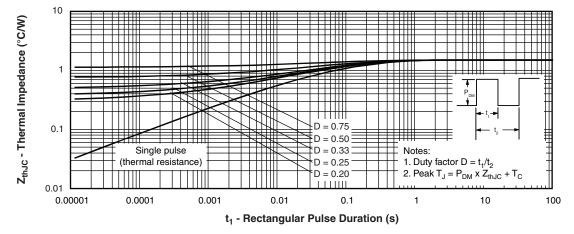


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics



www.vishay.com

Vishay Semiconductors

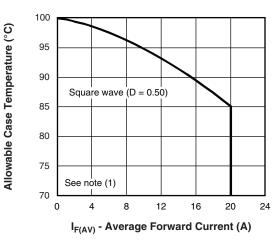


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current

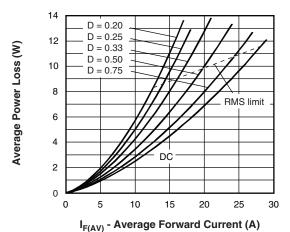


Fig. 6 - Forward Power Loss Characteristics

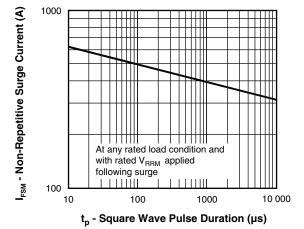


Fig. 7 - Maximum Non-Repetitive Surge Current

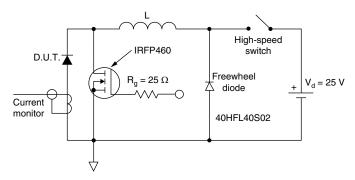


Fig. 8 - Unclamped Inductive Test Circuit

Note

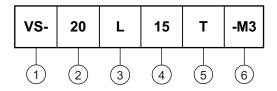
(1) Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{th,JC}$; $Pd = forward power loss = I_{F(AV)} \times V_{FM} at (I_{F(AV)}/D)$ (see fig. 6); $Pd_{REV} = inverse power loss = V_{R1} \times I_R (1 - D)$; I_R at $V_{R1} = 80 \%$ rated V_R



Vishay Semiconductors

ORDERING INFORMATION TABLE

Device code



1 - Vishay Semiconductors product

Current rating (20 = 20 A)

3 - Schottky "L" series

- Voltage code (15 = 15 V)

5 - Package

T = TO-220

6 - Environmental digit

-M3 = halogen-free, RoHS-compliant, and termination lead (Pb)-free

ORDERING INFORMATION (Example)							
PREFERRED P/N	BASE QUANTITY	PACKAGING DESCRIPTION					
VS-20L15T-M3	50	Antistatic plastic tubes					

LINKS TO RELATED DOCUMENTS						
Dimensions www.vishay.com/doc?96156						
Part marking information	www.vishay.com/doc?95391					
SPICE model	www.vishay.com/doc?97117					



Vishay Semiconductors

TO-220AC 2L

DIMENSIONS in millimeters and inches





Conforms to JEDEC® outline TO-220AC

SYMBOL	MILLIMETERS		INCHES		S NOTES		SYMBOL	MILLIN	IETERS	INC	HES	NOTES
STMBOL	MIN.	MAX.	MIN.	MAX.	NOTES	NOTES	STIVIBOL	MIN.	MAX.	MIN.	MAX.	NOTES
Α	4.25	4.65	0.167	0.183			D2	11.68	13.30	0.460	0.524	6, 7
A1	1.14	1.40	0.045	0.055			Е	10.11	10.51	0.398	0.414	3, 6
A2	2.50	2.92	0.098	0.115			E1	6.86	8.89	0.270	0.350	6
b	0.69	1.01	0.027	0.040			е	2.41	2.67	0.095	0.105	
b1	0.38	0.97	0.015	0.038	4		e1	4.88	5.28	0.192	0.208	
b2	1.20	1.73	0.047	0.068			H1	6.09	6.48	0.240	0.255	6
b3	1.14	1.73	0.045	0.068	4		L	13.52	14.02	0.532	0.552	
С	0.36	0.61	0.014	0.024			L1	3.32	3.82	0.131	0.150	2
c1	0.36	0.56	0.014	0.022	4		ØΡ	3.54	3.91	0.139	0.154	
D	14.85	15.35	0.585	0.604	3		Q	2.60	3.00	0.102	0.118	
D1	8.38	9.02	0.330	0.355				•	•			

Notes

- ⁽¹⁾ Dimensioning and tolerancing as per ASME Y14.5M-1994
- (2) Lead dimension and finish uncontrolled in L1
- (3) Dimension D, D1, and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body
- (4) Dimension b1, b3, and c1 apply to base metal only
- Controlling dimensions: inches
- (6) Thermal pad contour optional within dimensions E, H1, D2, and E1
- (7) Outline conforms to JEDEC® TO-220, except D2



Legal Disclaimer Notice

Vishay

Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and / or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Hyperlinks included in this datasheet may direct users to third-party websites. These links are provided as a convenience and for informational purposes only. Inclusion of these hyperlinks does not constitute an endorsement or an approval by Vishay of any of the products, services or opinions of the corporation, organization or individual associated with the third-party website. Vishay disclaims any and all liability and bears no responsibility for the accuracy, legality or content of the third-party website or for that of subsequent links.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.